Features

- · Low-voltage and Standard-voltage Operation
 - $2.7 (V_{CC} = 2.7V \text{ to } 5.5V)$
 - $1.8 (V_{CC} = 1.8V \text{ to } 5.5V)$
- User-selectable Internal Organization
 - 1K: 128 x 8 or 64 x 16
- Three-wire Serial Interface
- 2 MHz Clock Rate (5V)
- Self-timed Write Cycle (10 ms max)
- High Reliability
 - Endurance: 1 Million Write Cycles
 - Data Retention: 100 Years
- Automotive Grade Devices Available
- 8-lead JEDEC PDIP, 8-lead JEDEC SOIC, 8-lead EIAJ SOIC, 8-lead Ultra Thin mini-MAP (MLP 2x3), 8-lead TSSOP and 8-ball dBGA2 Packages

Description

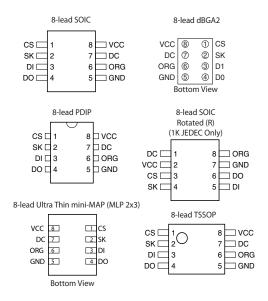
The AT93C46 provides 1024 bits of serial electrically erasable programmable readonly memory (EEPROM), organized as 64 words of 16 bits each (when the ORG pin is connected to VCC), and 128 words of 8 bits each (when the ORG pin is tied to ground). The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The AT93C46 is available in space-saving 8-lead PDIP, 8-lead JEDEC SOIC, 8-lead EIAJ SOIC, 8-lead Ultra Thin mini-MAP (MLP 2x3), 8-lead TSSOP, and 8-lead dBGA2 packages.

The AT93C46 is enabled through the Chip Select pin (CS) and accessed via a three-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a Read instruction at DI, the address is decoded and the data is clocked out serially on the DO pin. The Write cycle is completely self-timed, and no separate Erase cycle is required before Write. The Write cycle is only enabled when the part is in the Erase/Write Enable state. When CS is brought high following the initiation of a Write cycle, the DO pin outputs the Ready/Busy status of the part.

The AT93C46 is available in 2.7V to 5.5V and 1.8V to 5.5V versions.

Table 1. Pin Configurations

Pin Name	Function	
CS	Chip Select	
SK	Serial Data Clock	
DI	Serial Data Input	
DO	Serial Data Output	
GND	Ground	
VCC	Power Supply	
ORG	Internal Organization	
DC	Don't Connect	





Three-wire Serial EEPROM

1K (128 x 8 or 64 x 16)

AT93C46

Note: Not recommended for new design; please refer to AT93C46D datasheet.



5140B-SEEPR-2/07





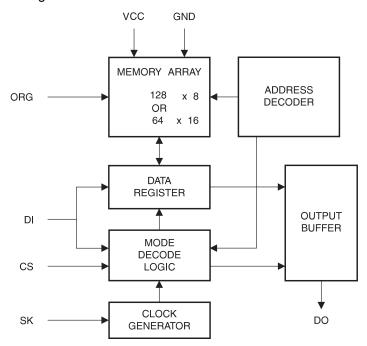
Absolute Maximum Ratings*

Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground1.0V to +7.0V
Maximum Operating Voltage 6.25V
DC Output Current

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

Figure 1. Block Diagram



Note: When the ORG pin is connected to VCC, the "x 16" organization is selected. When it is connected to ground, the "x 8" organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the "x 16" organization is selected. The feature is not available on the 1.8V devices.

For the AT93C46, if "x 16" organization is the mode of choice and Pin 6 (ORG) is left unconnected, Atmel recommends using the AT93C46A device. For more details, see the AT93C46A datasheet.

Table 2. Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^{\circ}C$, f = 1.0 MHz, $V_{CC} = +5.0$ V (unless otherwise noted)

Symbol	Test Conditions	Max	Units	Conditions
C _{OUT}	Output Capacitance (DO)	5	pF	V _{OUT} = 0V
C _{IN}	Input Capacitance (CS, SK, DI)	5	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

Table 3. DC Characteristics

Applicable over recommended operating range from: T_{AI} = -40°C to +85°C, V_{CC} = +1.8V to +5.5V, T_{AE} = -40°C to +125°C, V_{CC} = +1.8V to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Unit
V _{CC1}	Supply Voltage			1.8		5.5	V
V _{CC2}	Supply Voltage			2.7		5.5	V
V _{CC3}	Supply Voltage			4.5		5.5	V
	Cupply Current	\/ = F 0\/	READ at 1.0 MHz		0.5	2.0	mA
I _{CC}	Supply Current	V _{CC} = 5.0V	WRITE at 1.0 MHz		0.5	2.0	mA
I _{SB1}	Standby Current	V _{CC} = 1.8V	CS = 0V		0	0.1	μΑ
I _{SB2}	Standby Current	V _{CC} = 2.7V	V _{CC} = 2.7V		6.0	10.0	μΑ
I _{SB3}	Standby Current	V _{CC} = 5.0V	CS = 0V		17	30	μΑ
I _{IL}	Input Leakage	V _{IN} = 0V to V _{CC}	V _{IN} = 0V to V _{CC}		0.1	1.0	μΑ
I _{OL}	Output Leakage	V _{IN} = 0V to V _{CC}	V _{IN} = 0V to V _{CC}		0.1	1.0	μΑ
V _{IL1} ⁽¹⁾	Input Low Voltage	2.7\/ < \	/	-0.6		0.8	V
V _{IH1} ⁽¹⁾	Input High Voltage	Z.7 V ≤ V	′ _{CC} ≤ 5.5V	2.0		V _{CC} + 1	
V _{IL2} ⁽¹⁾	Input Low Voltage	4.0\/.<\	/ < 2.7\/	-0.6		V _{CC} x 0.3	V
V _{IH2} ⁽¹⁾	Input High Voltage	- 1.8V ≤ V	′ _{CC} ≤ 2.7V	V _{CC} x 0.7		V _{CC} + 1	V
V _{OL1}	Output Low Voltage	0.7\/ .\/	I _{OL} = 2.1 mA			0.4	V
V _{OH1}	Output High Voltage	$2.7V \le V_{CC} \le 5.5V$	I _{OH} = -0.4 mA	2.4			V
V _{OL2}	Output Low Voltage	I _{OL} = 0.15 mA				0.2	V
V _{OH2}	Output High Voltage	$1.8V \le V_{CC} \le 2.7V$	I _{OH} = -100 μA	V _{CC} - 0.2			V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.





Table 4. AC Characteristics

Applicable over recommended operating range from T_{AI} = -40° C to + 85° C, V_{CC} = As Specified, CL = 1 TTL Gate and 100 pF (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
f _{SK}	SK Clock Frequency	$ 4.5V \le V_{CC} \le 5.5V \\ 2.7V \le V_{CC} \le 5.5V \\ 1.8V \le V_{CC} \le 5.5V $	1	0 0 0		2 1 0.25	MHz
t _{SKH}	SK High Time	$\begin{array}{c} 4.5 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \\ 2.7 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \\ 1.8 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \end{array}$	/	250 250 1000			ns
t _{SKL}	SK Low Time	$\begin{array}{c} 4.5 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \\ 2.7 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \\ 1.8 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \end{array}$	/	250 250 1000			ns
t _{CS}	Minimum CS Low Time	$\begin{array}{c} 4.5 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \\ 2.7 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \\ 1.8 \text{V} \leq \text{V}_{CC} \leq 5.5 \text{V} \end{array}$	/	250 250 1000			ns
t _{CSS}	CS Setup Time	Relative to SK	$ 4.5V \le V_{CC} \le 5.5V \\ 2.7V \le V_{CC} \le 5.5V \\ 1.8V \le V_{CC} \le 5.5V $	50 50 200			ns
t _{DIS}	DI Setup Time	Relative to SK	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 1.8V \leq V_{CC} \leq 5.5V \end{array}$	100 100 400			ns
t _{CSH}	CS Hold Time	Relative to SK		0			ns
t _{DIH}	DI Hold Time	Relative to SK	$\begin{array}{c} 4.5 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \\ 2.7 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \\ 1.8 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \end{array}$	100 100 400			ns
t _{PD1}	Output Delay to "1"	AC Test	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 1.8V \leq V_{CC} \leq 5.5V \end{array}$			250 250 1000	ns
t _{PD0}	Output Delay to "0"	AC Test	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 1.8V \leq V_{CC} \leq 5.5V \end{array}$			250 250 1000	ns
t _{SV}	CS to Status Valid	AC Test	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 1.8V \leq V_{CC} \leq 5.5V \end{array}$			250 250 1000	ns
t _{DF}	CS to DO in High Impedance	AC Test CS = V _{IL}	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 1.8V \leq V_{CC} \leq 5.5V \end{array}$			100 100 400	ns
+	Write Cyclo Time	•				10	ms
t _{WP}	Write Cycle Time	the Time $4.5V \le V_{CC} \le 5.5V$		0.1	3		ms
Endurance ⁽¹⁾	5.0V, 25°C			1M			Write Cycles

Note: 1. This parameter is characterized and is not 100% tested.

Table 5. Instruction Set for the AT93C46

		Op	Add	ress	Data		
Instruction	SB	Code	x 8	x 16	x 8	x 16	Comments
READ	1	10	$A_6 - A_0$	$A_5 - A_0$			Reads data stored in memory, at specified address
EWEN	1	00	11XXXXX	11XXXX			Write enable must precede all programming modes
ERASE	1	11	$A_6 - A_0$	$A_5 - A_0$			Erases memory location A _n – A ₀
WRITE	1	01	$A_6 - A_0$	$A_5 - A_0$	$D_7 - D_0$	D ₁₅ – D ₀	Writes memory location A _n – A ₀
ERAL	1	00	10XXXXX	10XXXX			Erases all memory locations. Valid only at V _{CC} = 4.5V to 5.5V
WRAL	1	00	01XXXXX	01XXXX	$D_7 - D_0$	D ₁₅ – D ₀	Writes all memory locations. Valid only at V _{CC} = 4.5V to 5.5V
EWDS	1	00	00XXXXX	00XXXX			Disables all programming instructions

Note: The Xs in the address field represent DON'T CARE values and must be clocked.

Functional Description

The AT93C46 is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. A valid instruction starts with a rising edge of CS and consists of a start bit (logic "1") followed by the appropriate op code and the desired memory address location.

READ (READ): The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 8- or 16-bit data output string.

ERASE/WRITE ENABLE (EWEN): To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or V_{CC} power is removed from the part.

ERASE (ERASE): The Erase (ERASE) instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the Erase instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic "1" at pin DO indicates that the selected memory location has been erased and the part is ready for another instruction.

WRITE (WRITE): The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle t_{WP} starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Read/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A Ready/Busy status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle tWP.





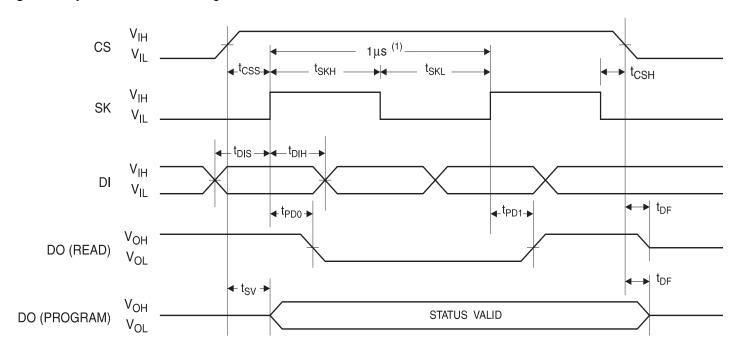
ERASE ALL (ERAL): The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The ERAL instruction is valid only at V_{CC} = 5.0V \pm 10%.

WRITE ALL (WRAL): The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The WRAL instruction is valid only at V_{CC} = 5.0V ± 10%.

ERASE/WRITE DISABLE (EWDS): To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

Timing Diagrams

Figure 2. Synchronous Data Timing



Note: 1. This is the minimum SK period.

 Table 6. Organization Key for Timing Diagrams

	AT93C46 (1K)		
I/O	x 8	x 16	
A _N	A ₆	A ₅	
D _N	D ₇	D ₁₅	

Figure 3. READ Timing

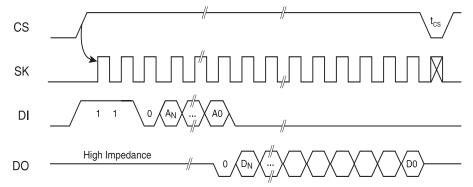


Figure 4. EWEN Timing

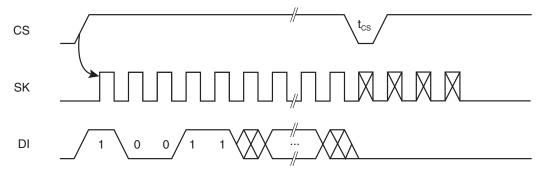


Figure 5. EWDS Timing

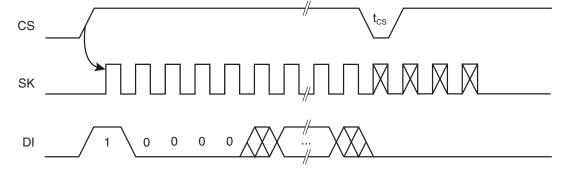




Figure 6. WRITE Timing

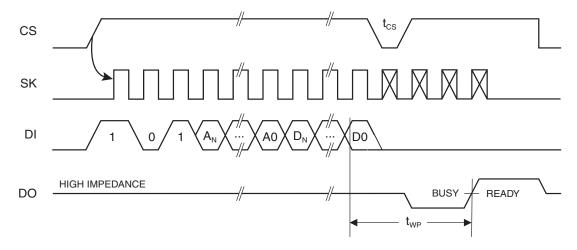
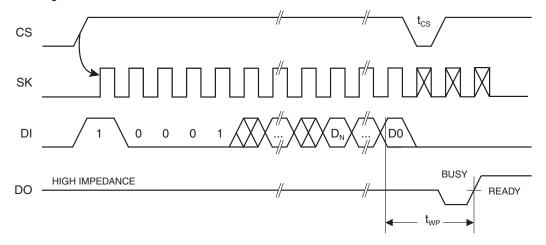


Figure 7. WRAL Timing⁽¹⁾



Note: 1. Valid only at $V_{CC} = 4.5V$ to 5.5V.

Figure 8. ERASE Timing

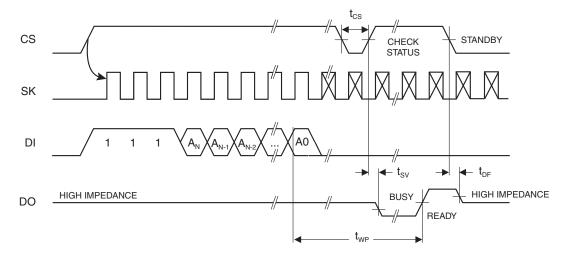
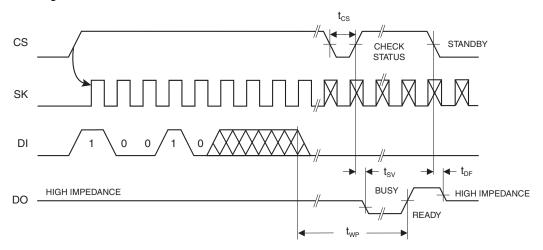


Figure 9. ERAL Timing⁽¹⁾



Note: 1. Valid only at $V_{CC} = 4.5V$ to 5.5V.





AT93C46 Ordering Information⁽¹⁾

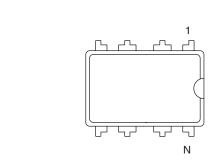
Ordering Code	Package	Operation Range
AT93C46-10PU-2.7 ⁽²⁾ AT93C46-10PU-1.8 ⁽²⁾ AT93C46-10SU-2.7 ⁽²⁾ AT93C46-10SU-1.8 ⁽²⁾ AT93C46W-10SU-2.7 ⁽²⁾ AT93C46W-10SU-1.8 ⁽²⁾ AT93C46-10TU-2.7 ⁽²⁾ AT93C46-10TU-1.8 ⁽²⁾ AT93C46Y1-10YU-1.8 ⁽²⁾ (Not recommended for new designs) AT93C46Y1-10YH-1.8 ⁽³⁾ AT93C46U3-10UU-1.8 ⁽²⁾	8P3 8P3 8S1 8S1 8S2 8S2 8A2 8A2 8A2 8A1 8Y6	Lead-free/Halogen-free/ Industrial Temperature (-40°C to 85°C)
AT93C46-W1.8-11 ⁽⁴⁾	Die Sale	Industrial (-40°C to 85°C)

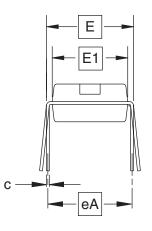
- Notes: 1. For 2.7V devices used in the 4.5V to 5.5V range, please refer to performance values in the Table 3 on page 3 and Table 4 on page 4. Not recommended for new design. Please refer to AT93C46D datasheet.
 - 2. "U" designates Green Package and RoHS compliant.
 - 3. "H" designates Green Package and RoHS compliant, with NiPdAu Lead finish
 - 4. Available in waffle pack and wafer form, order as SL788 for inkless wafer form. Bumped die available upon request.

	Package Type			
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)			
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)			
8S2	8-lead, 0.200" Wide, Plastic Gull Wing Small Outline (EIAJ SOIC)			
8A2	8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)			
8U3-1	8-ball, Die Ball Grid Array Package (dBGA2)			
8Y1	8-lead, 4.90 mm x 3.00 mm Body, Dual Footprint, Non-leaded, Miniature Array Package (MAP)			
8Y6	8-lead, 2.00 mm x 3.00 mm Body, 0.50mm Pitch, Ultra-Thin Mini-MAO, Dual No Lead Package. (DFN), (MLP 2x3mm)			
	Options			
-2.7	Low Voltage (2.7V to 5.5V)			
-1.8	Low Voltage (1.8V to 5.5V)			
R	Rotated Pinout			

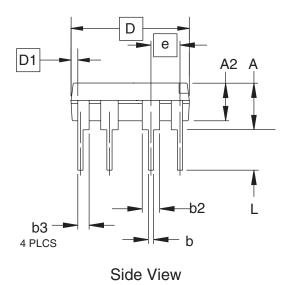
Packaging Information

8P3 - PDIP





End View



Top View

COMMON DIMENSIONS

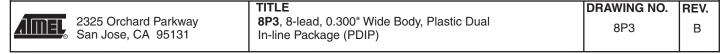
(Unit of Measure = inches)

SYMBOL	MIN	NOM	MAX	NOTE
Α			0.210	2
A2	0.115	0.130	0.195	
b	0.014	0.018	0.022	5
b2	0.045	0.060	0.070	6
b3	0.030	0.039	0.045	6
С	0.008	0.010	0.014	
D	0.355	0.365	0.400	3
D1	0.005			3
Е	0.300	0.310	0.325	4
E1	0.240	0.250	0.280	3
е	(
eA	(4		
L	0.115	0.130	0.150	2

Notes

- 1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
- 2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
- 3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
- 4. E and eA measured with the leads constrained to be perpendicular to datum.
- 5. Pointed or rounded lead tips are preferred to ease insertion.
- 6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

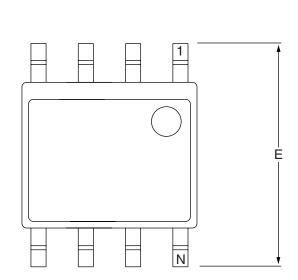
01/09/02



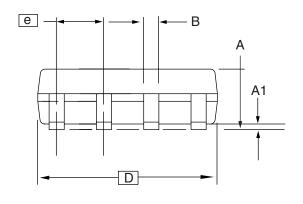




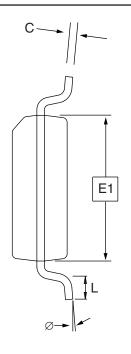
8S1 - JEDEC SOIC



Top View



Side View



End View

COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
А	1.35	-	1.75	
A1	0.10	-	0.25	
b	0.31	_	0.51	
С	0.17	-	0.25	
D	4.80	_	5.00	
E1	3.81	_	3.99	
Е	5.79	_	6.20	
е				
L	0.40	_	1.27	
Ø	0°	_	8°	

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

10/7/03

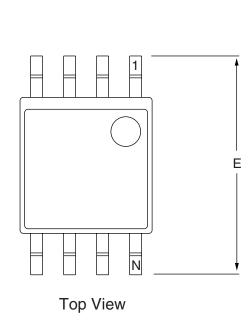
<u>AIMEL</u>

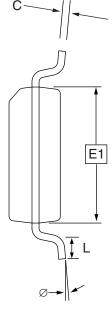
1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906

TITLE
8S1, 8-lead (0.150" Wide Body), Plastic Gull Wing
Small Outline (JEDEC SOIC)

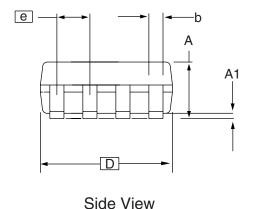
REV.
В

8S2 - EIAJ SOIC









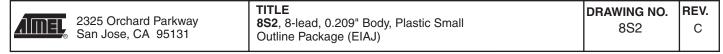
COMMON DIMENSIONS (Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	1.70		2.16	
A1	0.05		0.25	
b	0.35		0.48	5
С	0.15		0.35	5
D	5.13		5.35	
E1	5.18		5.40	2, 3
E	7.70		8.26	
L	0.51		0.85	
Ø	0°		8°	
е	1.27 BSC		4	

- Notes: 1. This drawing is for general information only; refer to EIAJ Drawing EDR-7320 for additional information.
 2. Mismatch of the upper and lower dies and resin burrs are not included.

 - 3. It is recommended that upper and lower cavities be equal. If they are different, the larger dimension shall be regarded.
 - 4. Determines the true geometric position.
 - 5. Values b and C apply to pb/Sn solder plated terminal. The standard thickness of the solder layer shall be 0.010 +0.010/-0.005 mm.

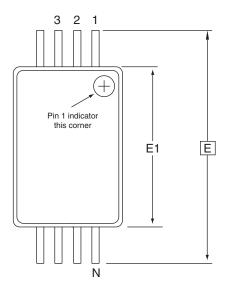
10/7/03



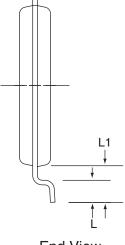




8A2 - TSSOP



Top View



End View

COMMON DIMENSIONS

(Unit of Measure = mm)

1.00 REF

NOTE

2, 5

3, 5

4

MAX

3.10

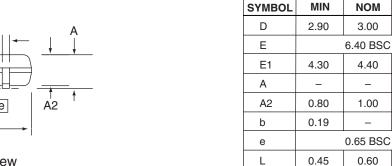
4.50

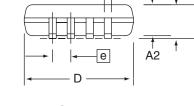
1.20

1.05

0.30

0.75





Side View

- Notes: 1. This drawing is for general information only. Refer to JEDEC Drawing MO-153, Variation AA, for proper dimensions, tolerances, datums, etc.
 - 2. Dimension D does not include mold Flash, protrusions or gate burrs. Mold Flash, protrusions and gate burrs shall not exceed 0.15 mm (0.006 in) per side.

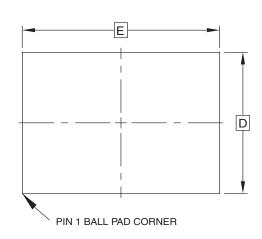
L1

- 3. Dimension E1 does not include inter-lead Flash or protrusions. Inter-lead Flash and protrusions shall not exceed 0.25 mm (0.010 in) per side.
- 4. Dimension b does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the b dimension at maximum material condition. Dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and adjacent lead is 0.07 mm.
- 5. Dimension D and E1 to be determined at Datum Plane H.

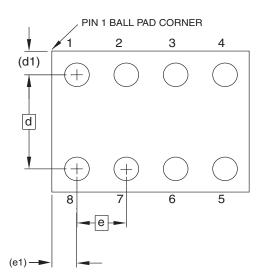
5/30/02

		TITLE	DRAWING NO.	REV.
<u>Alm</u>	2325 Orchard Parkway San Jose, CA 95131	8A2, 8-lead, 4.4 mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)	8A2	В

8U3-1 - dBGA2



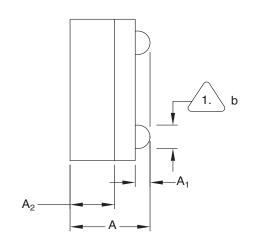
Top View



Bottom View 8 SOLDER BALLS

1. Dimension "b" is measured at the maximum solder ball diameter.

This drawing is for general information only.



Side View

COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	0.71	0.81	0.91	
A1	0.10	0.15	0.20	
A2	0.40	0.45	0.50	
b	0.20	0.25	0.30	
D	1.50 BSC			
Е	2.00 BSC			
е	0.50 BSC			
e1	0.25 REF			
d	1.00 BSC			
d1	0.25 REF			

6/24/03



1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 8U3-1, 8-ball, 1.50 x 2.00 mm Body, 0.50 mm pitch, Small Die Ball Grid Array Package (dBGA2)

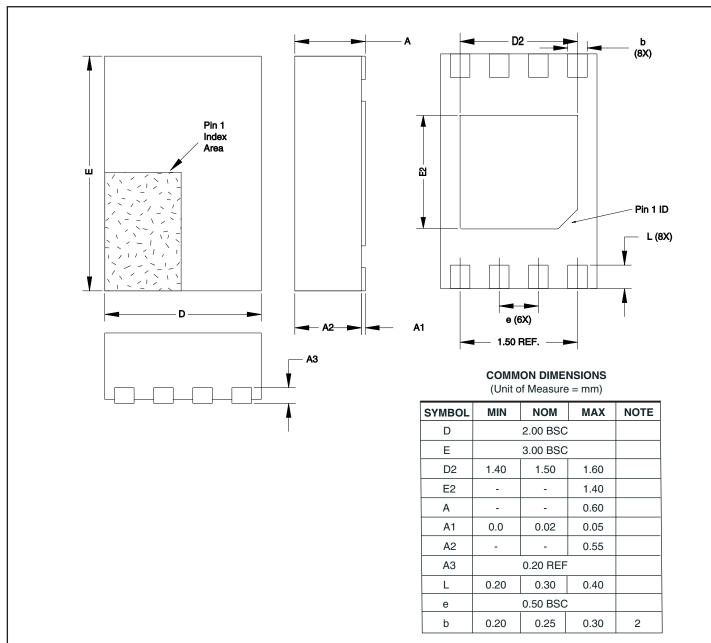
DRAWING NO. PO8U3-1

REV.





8Y6 - Mini-MAP



Notes:

- 1. This drawing is for general information only. Refer to JEDEC Drawing MO-229, for proper dimensions, tolerances, datums, etc.
- 2. Dimension b applies to metallized terminal and is measured between 0.15 mm and 0.30 mm from the terminal tip. If the terminal has the optional radius on the other end of the terminal, the dimension should not be measured in that radius area.

8/26/05

		DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	8Y6 , 8-lead 2.0 x 3.0 mm Body, 0.50 mm Pitch, Utlra Thin Mini-Map, Dual No Lead Package (DFN) ,(MLP 2x3)	8Y6	С

Revision History

Doc. Rev.	Date	Comments
5140B	2/2007	Implemented revision history.
		Added note to page 1 and ordering information; 'Not recommended for new design; please refer to AT93C46D datasheet'.





Atmel Corporation

2325 Orchard Parkway San Jose, CA 95131, USA Tel: 1(408) 441-0311

Fax: 1(408) 487-2600

Regional Headquarters

Europe

Atmel Sarl Route des Arsenaux 41 Case Postale 80 CH-1705 Fribourg Switzerland

Tel: (41) 26-426-5555 Fax: (41) 26-426-5500

Asia

Room 1219 Chinachem Golden Plaza 77 Mody Road Tsimshatsui East Kowloon Hong Kong

Tel: (852) 2721-9778 Fax: (852) 2722-1369

Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan

Tel: (81) 3-3523-3551 Fax: (81) 3-3523-7581

Atmel Operations

Memory

2325 Orchard Parkway San Jose, CA 95131, USA Tel: 1(408) 441-0311 Fax: 1(408) 436-4314

Microcontrollers

2325 Orchard Parkway San Jose, CA 95131, USA Tel: 1(408) 441-0311 Fax: 1(408) 436-4314

La Chantrerie BP 70602 44306 Nantes Cedex 3, France Tel: (33) 2-40-18-18-18 Fax: (33) 2-40-18-19-60

ASIC/ASSP/Smart Cards

Zone Industrielle 13106 Rousset Cedex, France Tel: (33) 4-42-53-60-00

Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906, USA

Tel: 1(719) 576-3300 Fax: 1(719) 540-1759

Scottish Enterprise Technology Park Maxwell Building East Kilbride G75 0QR, Scotland

Tel: (44) 1355-803-000 Fax: (44) 1355-242-743

RF/Automotive

Theresienstrasse 2 Postfach 3535 74025 Heilbronn, Germany Tel: (49) 71-31-67-0 Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd. Colorado Springs, CO 80906, USA

Tel: 1(719) 576-3300 Fax: 1(719) 540-1759

Biometrics/Imaging/Hi-Rel MPU/ High Speed Converters/RF Datacom

Avenue de Rochepleine BP 123

38521 Saint-Egreve Cedex, France

Tel: (33) 4-76-58-30-00 Fax: (33) 4-76-58-34-80

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